Unit: mm

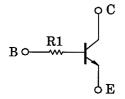
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

# RN1412,RN1413

Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

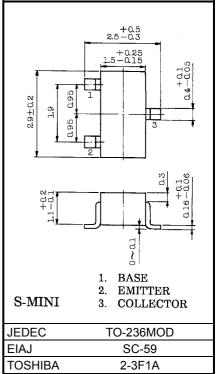
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN2412, RN2413

## **Equivalent Circuit**



### **Maximum Ratings (Ta = 25°C)**

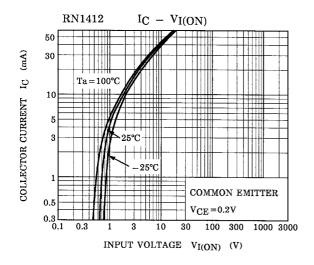
Characteristic	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	50	V
Collector-emitter voltage	V <sub>CEO</sub>	50	٧
Emitter-base voltage	V <sub>EBO</sub>	5	٧
Collector current	IC	100	mA
Collector power dissipation	PC	200	mW
Junction temperature	Tj	150	°C
Storage temperature range	T <sub>stg</sub>	-55~125	°C

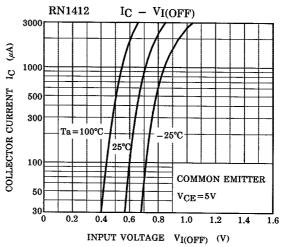


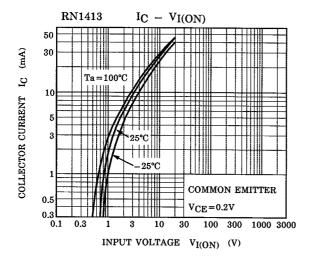
Weight: 0.012g

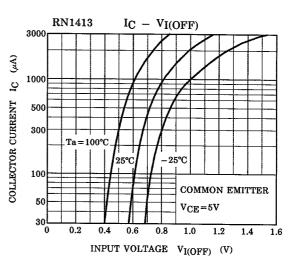
#### **Electrical Characteristics (Ta = 25°C)**

Characteristic		Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I <sub>CBO</sub>	_	V <sub>CB</sub> = 50V, I <sub>E</sub> = 0	_	_	100	nA
Emitter cut-off current		I <sub>EBO</sub>	_	V <sub>EB</sub> = 5V, I <sub>C</sub> = 0	_	_	100	nA
DC current gain		h <sub>FE (note)</sub>	_	V <sub>CE</sub> = 5V, I <sub>C</sub> = 1mA	120	_	700	
Collector-emitter saturation voltage		V <sub>CE (sat)</sub>	_	I <sub>C</sub> = 5mA, I <sub>B</sub> = 0.25mA	_	0.1	0.3	V
Transition frequency		f <sub>T</sub>	_	V <sub>CE</sub> = 10V, I <sub>C</sub> = 5mA	_	250	_	MHz
Collector output capacitance		C <sub>ob</sub>	_	V <sub>CB</sub> = 10V, I <sub>E</sub> = 0, f = 1MHz	_	3	6	pF
Input resistor	RN1412	- R1	_	_	15.4	22	28.6	kΩ
	RN1413				32.9	47	61.1	K7.2

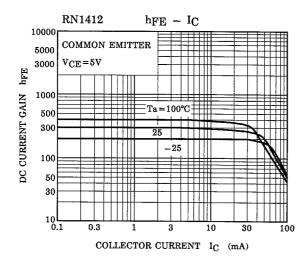


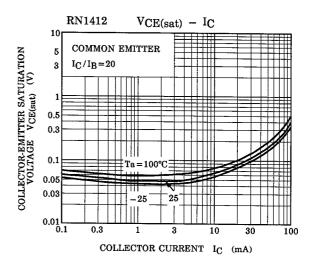


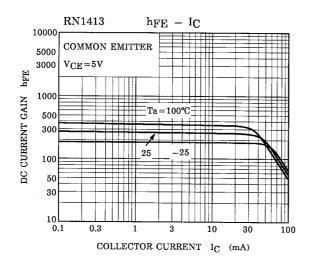


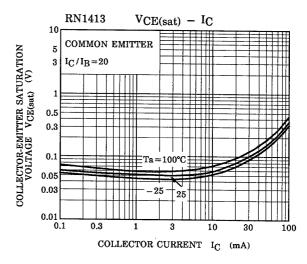


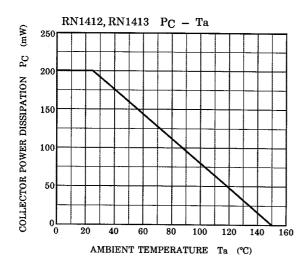
2 2001-06-07











3 2001-06-07

Type Name	Marking	
RN1412	Type Name  X N	
RN1413	Type Name X P	

2001-06-07

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